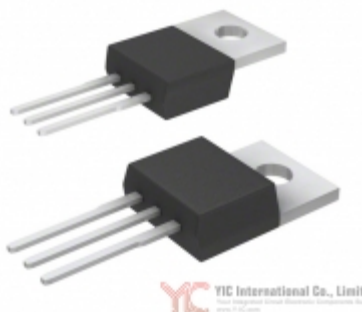






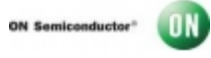


	<h2 style="color: red;">NTP60N06</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">NTP60N06</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 60V 60A TO220AB
<b>Datenblätter:</b>	 <a href="#">NTP60N06.pdf</a>	
<b>RoHs Status:</b>	Enthält Blei / RoHS nicht konform	
<b>Lagerzustand:</b>	New original, 45509 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	<a href="#">NTP60N06</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 60V 60A TO220AB
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	45509 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	2.4W (Ta), 150W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Ta)
Rds On (Max) @ Id, Vgs	14 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	81nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3220pF @ 25V
Verpackung	Tube



















































NTP60N06 ist neu im Original. Suche NTP60N06 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP60N06 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP60N06: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTP6410AN</b> ON NTP6410AN ON</p>	 <p><b>NTP5864NG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 63A TO-220</p>	 <p><b>NTP60N06G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p>	 <p><b>NTP6410ANG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 76A TO-220</p>
 <p><b>NTP5863N</b> VB NTP5863N VB</p>	 <p><b>NTP5864N</b> AMI Semiconductor / ON Semiconductor NTP5864N ON</p>	 <p><b>NTP60N06L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p>	 <p><b>NTP60N06LG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p>

### heiße Teile

Mehr

 NTP35N15	 NTP35N15G	 NTP4302G	 NTP45N06	 NTP45N06G
 NTP45N06L	 NTP45N06LG	 NTP477M04TDR	 NTP52N10	 NTP52N10G
 NTP5404N	 NTP5404NRG	 NTP5411NG	 NTP5412NG	 NTP5426N
 NTP5426NG	 NTP5860N	 NTP5860NG	 NTP5860NL	 NTP5860NLG
 NTP5862NG	 NTP5863N	 NTP5863NG	 NTP5864N	 NTP5864NG
 NTP60N06G	 NTP60N06L	 NTP60N06LG	 NTP6410AN	 NTP6410ANG
 NTP6411AN	 NTP6411ANG	 NTP6412AN	 NTP6412ANG	 NTP6413AN
 NTP6413ANG	 NTP6448ANG	 NTP65N02R	 NTP65N02RG	 NTP75N03-006
 NTP75N03-06	 NTP75N03-06G	 NTP75N03-6G	 NTP75N03L09	 NTP75N03L09G
 NTP75N03R	 NTP75N03RG	 NTP75N06	 NTP75N06D	 NTP75N06G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited